# 2SC5592

## Silicon NPN epitaxial planer type

For DC-DC converter
For various driver circuits

### Features

- $\bullet$  Low collector to emitter saturation voltage  $V_{\text{CE}(\text{sat})}$  , large current capacitance
- High-speed switching
- Mini type 3-pin package, allowing downsizing and thinning of the equipment.
- Complementary pair with 2SA2010

## ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Collector to base voltage	V <sub>CBO</sub>	15	V
Collector to emitter voltage	V <sub>CEO</sub>	15	V
Emitter to base voltage	V <sub>EBO</sub>	5	V
Peak collector current	$I_{CP}$	10	A
Collector current	$I_{C}$	2.5	A
Collector power dissipation *	P <sub>C</sub>	600	mW
Junction temperature	Tj	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

Note) \*: Measure on the ceramic substrate at  $15 \times 15 \times 0.6$  mm<sup>3</sup>.

# Unit: mm 0.40<sup>+0.10</sup><sub>-0.05</sub> 0.16<sup>+0.10</sup><sub>-0.06</sub> 0.16<sup>+0.10</sup><sub>-0.06</sub> 1. Base 2. Emitter 3: Collector EIAJ: SC-59 Mini Type Package (3-pin)

Marking Symbol: 2T

## ■ Electrical Characteristics T<sub>a</sub> = 25°C ± 3°C

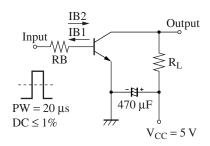
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff current	$I_{CBO}$	$V_{CB} = 10 \text{ V}, I_{E} = 0$			0.1	μΑ
Collector to base voltage	$V_{CBO}$	$I_C = 10 \mu\text{A},  I_E =  0$	15		- 1	V
Collector to emitter voltage	V <sub>CEO</sub>	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	15			V
Emitter to base voltage	$V_{EBO}$	$I_E = 10 \mu\text{A},  I_C = 0$	5			V
Forward current transfer ratio *1	h <sub>FE1</sub>	$V_{CE} = 2 \text{ V}, I_{C} = 100 \text{ mA}$	400		1 000	
	h <sub>FE2</sub>	$V_{CE} = 2 \text{ V}, I_{C} = 2.5 \text{ A}$	280			
Collector to emitter saturation voltage *1	V <sub>CE(sat)</sub>	$I_C = 1 \text{ A}, I_B = 10 \text{ mA}$		110		mV
_ LET   TE		$I_C = 2.5 \text{ A}, I_B = 50 \text{ mA}$		220	320	mV
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		30		pF
Transition frequency	$f_T$	$V_{CB} = 10 \text{ V}, I_{E} = -50 \text{ mA}$ f = 200  MHz		180		MHz
Turn-on time *2	t <sub>on</sub>			30		ns
Storage time *2	t <sub>stg</sub>			100		ns
Fall time PDF	$t_{\mathrm{f}}$			10		ns

Note) 1 Rank classification (≤ 1 ms)

of \*2; Refere to the measurement circuit.

2SC5592 Transistors

## ■ Measurement Circuit



-201B1 = 201B2 = IC = 1.5 A

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